# UNIVERSITI KUALA LUMPUR <br> Malaysia France Institute 

## FINAL EXAMINATION <br> SEPTEMBER 2013 SESSION

| SUBJECT CODE | $:$ FLB 12013 |
| :--- | :--- |
| SUBJECT TITLE | $:$ ANALOG ELECTRONICS |
| LEVEL | $:$ BACHELOR |
| TIME I DURATION | $: 2.5$ HOURS |
| DATE | $:$ |

INSTRUCTIONS TO CANDIDATES

1. Please read the instructions given in the question paper CAREFULLY.
2. This question paper is printed on both sides of the paper.
3. Please write your answers on the answer booklet provided.
4. Answers should be written in blue or black ink except for sketching, graphic and illustration.
5. This question paper consists of TWO (2) sections. Section A and B. Answer all questions in Section A. For Section B, answer three (3) questions only.
6. Answer all questions in English.

THERE ARE 7 PAGES OF QUESTIONS, EXCLUDING THIS PAGE.

## SECTION A (Total: 40 marks)

## INSTRUCTION: Answer ALL questions.

Please use the answer booklet provided.

## Question 1

(a) Define and briefly explain the doping process.
(b) Describe the conditions established by forward and reverse-bias states of the PNjunction diode.
(c) Draw an ideal and practical pn-junction diode characteristic curve.

## Question 2

Considering silicon diode, determine current I , voltage across the diode $\left(\mathrm{V}_{\mathrm{D}}\right)$, voltage drop across $\mathrm{R}_{1}\left(\mathrm{~V}_{1}\right)$ and output voltage ( $\mathrm{V}_{\text {OUT }}$ ).


Figure 1

## Question 3

Figure 2 shows a clipper circuit using two ideal silicon zener diodes with its respected output voltage, $\mathrm{V}_{\text {OUT }}$. For both question (a) and (b), please refer to data sheet attached in Appendix I and determine:


Figure 2
(a) The device type number of zener diode $D_{1}$ and $D_{2}$. Support your answer with calculation.
(b) The parameters value and unit for answer in (a).
(i) maximum DC Power Dissipation ( $\mathrm{P}_{\mathrm{D}}$ )
(ii) nominal Zener Voltage $\left(\mathbf{V}_{\mathbf{z}}\right)$
(iii) zener Knee Current ( $\mathrm{I}_{\mathrm{zk}}$ )
(iv) maximum Zener Test Impedance ( $\mathrm{Z}_{\mathrm{ZT}}$ )

## Question 4

A high sensor water module in Figure 3 below uses a bipolar junction transistor to energize and operate a $12 V_{D C}$ relay. The operation of the circuit is as follows: When sensor detects water, switch is closed and the transistor shall turn 'ON'. The relay then will be energized. Given $\beta=60$, determine $I_{B}, I_{C}, I_{E}, V_{B E}, V_{C E}$ and $V_{C B}$. (Transistor based on silicon).


Figure 3

## SECTION B (Total: 60 marks)

## INSTRUCTION: Answer THREE (3) questions only.

## Question 5

A positive full wave bridge rectifier is shown in Figure 4. Assume only silicon diodes are used in the rectifier. The turns ratio of the transformer is $10: 1$. Given input voltage is 115 Vrms 60 Hz . Answer the following questions.


Figure 4
(a) State two (2) advantages of bridge rectifier circuit.
(b) Explain the operation of the circuit.
(c) Calculate:
(i) The peak load current, $\mathrm{I}_{\mathrm{Lp}}$.
(ii) The average load current, $\mathrm{I}_{\text {Lavg }}$.
(4 marks)
(iii) Sketch the expected output waveform at point A and point B. (4 marks)

## Question 6

(a) (i) By referring to the zener voltage regulator circuit shown in Figure 5, calculate Iz. (Consider ideal zener diode).


IN968A Parameters:
$\mathrm{V}_{\mathrm{z}}=4.2 \mathrm{~V}$
$\mathrm{I}_{\mathrm{ZK}}=0.2 \mathrm{~mA}$
$I_{Z T}=15 \mathrm{~mA}$
$P_{D \max }=210 \mathrm{~mW}$

Figure 5
(ii) Determine whether zener diode IN968A used in circuit in Figure 5 can maintain its regulation. Give your reason for your answer.
(2 marks)
(b) By considering ideal zener diode, determine the minimum and maximum input voltages that can be regulated by the zener diode in Figure 6 below.
(10 marks)


IN4735 Parameters:
$\mathrm{V}_{\mathrm{Z}}=6 \mathrm{~V}$ at $\mathrm{I}_{\mathrm{ZT}}=20 \mathrm{~mA}$
$\mathrm{I}_{\mathrm{ZK}}=2 \mathrm{~mA}$
$P_{D}=1 \mathrm{~W}$ at $T_{L}=50^{\circ} \mathrm{C}$

Figure 6

## Question 7

(a) List out three (3) types of BJT circuit configurations.
(3 marks)
(b) Figure 7 shows silicon BJT in saturation condition and acts as a "fully ON" switch. List out four (4) saturation characteristics.
(4 marks)


Figure 7
(c) (i) Given the information appearing in Figure 8, determine $I_{C}, R_{C}, R_{B}$ and $V_{C E}$. Consider germanium based BJT.
(11 marks)
(ii) Find the saturation current $I_{\text {csat }}$ for the same circuit configuration.


Figure 8

## Question 8

(a) Prove that the closed-loop gain for non-inverting amplifier is $A_{C L}=1+\frac{R_{2}}{R_{1}}$ (6 marks)
(b) By using LM741 and its data sheets attached in Appendix II,
(i) Design an inverting amplifier that will deliver a $12 \mathrm{~V}_{\mathrm{pp}}$ output voltage to a $15 \mathrm{k} \Omega$ load resistance with a $50 \mathrm{mV}_{\mathrm{pk}}$ input voltage and maximum amplification is $30 \mathrm{~V}_{\mathrm{pp}}$. (Include the 8-pin DIP pin numbers in your schematic diagram).
(8 marks)
(ii) Determine the maximum allowable input voltage, $\mathrm{V}_{\text {INmax }}$.
(iii) $\quad$ Sketch $\mathrm{V}_{\mathbb{I N}}$ and $\mathrm{V}_{\text {OUt }}$ on the same curve.

## END OF QUESTION PAPER

## APPENDIX I

EAIRCHILD
SEMCONDUCTOR
1N4728A - 1N4764A

Zeners


DO-41 Glass case COLOR BAND DENOTES CATHODE

## Absolute Maximum Ratings ${ }^{*} T_{\mathrm{a}}=25^{\circ} \mathrm{C}$ unless othenwise noted

| Symbol | Parameter | Value | Units |
| :---: | :--- | :---: | :---: |
| $\mathrm{P}_{\mathrm{D}}$ | Power Dissipation <br> @ $\mathrm{TL} \leq 50^{\circ} \mathrm{C}$, Lead Length $=3 / 8^{\prime \prime}$ | 1.0 | W |
|  | Derate above $50^{\circ} \mathrm{C}$ | 6.67 | $\mathrm{~mW} /{ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{J}}, \mathrm{T}_{\text {STG }}$ | Operating and Storage Temperature Range | -65 to +200 | ${ }^{\circ} \mathrm{C}$ |

- These ratings are limiting values above which the serviceability of the diode may be impaired.

Electrical Characteristics $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$ uniess onemisise moled

| Device | $\mathbf{V}_{\mathbf{Z}}(\mathbf{V}) @ \mathbf{I}_{\mathbf{Z}}{ }^{\text {(Note 1) }}$ |  |  | $\begin{aligned} & \text { Test Current } \\ & I_{Z}(\mathrm{~mA}) \end{aligned}$ | Max. Zener Impedance |  |  | Leakage Current |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | Min. | Typ. | Max. |  | $\mathrm{Z}_{\mathrm{Z}} @ \mathrm{I}_{\mathrm{Z}}$ $(\Omega)$ | $\begin{aligned} & \mathrm{Z}_{\mathrm{ZK}} @ \\ & \mathrm{I}_{\mathrm{ZK}}(\Omega) \end{aligned}$ | $\begin{gathered} \mathrm{I}_{\mathrm{ZK}} \\ (\mathrm{~mA}) \end{gathered}$ | $\begin{gathered} \mathrm{I}_{\mathrm{R}} \\ (\mu \mathrm{~A}) \end{gathered}$ | $\begin{aligned} & V_{R} \\ & (V) \end{aligned}$ |
| 1N4728A | 3.315 | 3.3 | 3.465 | 76 | 10 | 400 | 1 | 100 | 1 |
| 1N4729A | 3.42 | 3.6 | 3.78 | 69 | 10 | 400 | 1 | 100 | 1 |
| 1N4730A | 3.705 | 3.9 | 4.095 | 64 | 9 | 400 | 1 | 50 | 1 |
| 1N4731A | 4.085 | 4.3 | 4.515 | 58 | 9 | 400 | 1 | 10 | 1 |
| 1N4732A | 4.465 | 4.7 | 4.935 | 53 | 8 | 500 | 1 | 10 | 1 |
| 1N4733A | 4.845 | 5.1 | 5.355 | 49 | 7 | 550 | 1 | 10 | 1 |
| 1N4734A | 5.32 | 5.6 | 5.88 | 45 | 5 | 600 | 1 | 10 | 2 |
| 1N4735A | 5.89 | 6.2 | 6.51 | 41 | 2 | 700 | 1 | 10 | 3 |
| 1N4736A | 6.46 | 6.8 | 7.14 | 37 | 3.5 | 700 | 1 | 10 | 4 |
| 1N4737A | 7.125 | 7.5 | 7.875 | 34 | 4 | 700 | 0.5 | 10 | 5 |
| 1N4738A | 7.79 | 8.2 | 8.61 | 31 | 4.5 | 700 | 0.5 | 10 | 6 |
| 1N4739A | 8.645 | 9.1 | 9.555 | 28 | 5 | 700 | 0.5 | 10 | 7 |
| 1N4740A | 9.5 | 10 | 10.5 | 25 | 7 | 700 | 0.25 | 10 | 7.6 |
| 1N4741A | 10.45 | 11 | 11.55 | 23 | 8 | 700 | 0.25 | 5 | 8.4 |
| 1N4742A | 11.4 | 12 | 12.6 | 21 | 9 | 700 | 0.25 | 5 | 9.1 |
| 1N4743A | 12.35 | 13 | 13.65 | 19 | 10 | 700 | 0.25 | 5 | 9.9 |
| 1N4744A | 14.25 | 15 | 15.75 | 17 | 14 | 700 | 0.25 | 5 | 11.4 |
| 1N4745A | 15.2 | 16 | 16.8 | 15.5 | 16 | 700 | 0.25 | 5 | 12.2 |
| 1N4746A | 17.1 | 18 | 18.9 | 14 | 20 | 750 | 0.25 | 5 | 13.7 |
| 1N4747A | 19 | 20 | 21 | 12.5 | 22 | 750 | 0.25 | 5 | 15.2 |

## APPENDIX II

## LM741 Operational Amplifier

## General Description

The LM741 series are general purpose operational amplifiers which feature improved performance over industry standards like the LM709. They are direct, plug-in replacements for the 709C, LM201, MC1439 and 748 in most applications.
The amplifiers offer many features which make their application nearly foolproof: overload protection on the input and
output, no latch-up when the common mode range is exceeded, as well as freedom from oscillations.
The LM741C/LM741E are identical to the LM741/LM741A except that the LM741C/LM741E have their performance guaranteed over a $0^{\circ} \mathrm{C}$ to $+70^{\circ} \mathrm{C}$ temperature range, instead of $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$.

## Schematic Diagram



TL/H/9341-1


TL/H/9341-7

Absolute Maximum Ratings
If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications. (Note 5)

|  | LM741A | LM741E | LM741 | LM741C |
| :--- | :---: | :---: | :---: | :---: |
| Supply Voltage | $\pm 22 \mathrm{~V}$ | $\pm 22 \mathrm{~V}$ | $\pm 22 \mathrm{~V}$ | $\pm 18 \mathrm{~V}$ |
| Power Dissipation (Note 1) | 500 mW | 500 mW | 500 mW | 500 mW |
| Differential Input Voltage | $\pm 30 \mathrm{~V}$ | $\pm 30 \mathrm{~V}$ | $\pm 30 \mathrm{~V}$ | $\pm 30 \mathrm{~V}$ |
| Input Voltage (Note 2) | $\pm 15 \mathrm{~V}$ | $\pm 15 \mathrm{~V}$ | $\pm 15 \mathrm{~V}$ | $\pm 15 \mathrm{~V}$ |
| Output Short Circuit Duration | Continuous | Continuous | Continuous | Continuous |
| Operating Temperature Range | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | $0^{\circ} \mathrm{C}$ to $+70^{\circ} \mathrm{C}$ | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | $0^{\circ} \mathrm{C}$ to $+70^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Junction Temperature | $150^{\circ} \mathrm{C}$ | $100^{\circ} \mathrm{C}$ | $150^{\circ} \mathrm{C}$ | $100^{\circ} \mathrm{C}$ |
| Soldering Information |  |  |  | $260^{\circ} \mathrm{C}$ |
| N-Package (10 seconds) | $260^{\circ} \mathrm{C}$ | $260^{\circ} \mathrm{C}$ | $300^{\circ} \mathrm{C}$ | $260^{\circ} \mathrm{C}$ |
| J- or H-Package (10 seconds) | $300^{\circ} \mathrm{C}$ | $300^{\circ} \mathrm{C}$ | $215^{\circ} \mathrm{C}$ | $300^{\circ} \mathrm{C}$ |
| M-Package |  | $215^{\circ} \mathrm{C}$ | $215^{\circ} \mathrm{C}$ | $215^{\circ} \mathrm{C}$ |

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.
ESD Tolerance (Note 6) 400V 400V 400V 400V

## Connection Diagrams



TL/H/9341-2
Order Number LM741H, LM741H/883*, LM741AH/883 or LM741CH See NS Package Number H08C


Order Number LM741J-14/883*, LM741AJ-14/883** See NS Package Number J14A

> *also available per JM38510/10101
> **also available per JM38510/10102

Dual-In-Line or S.O. Package


TL/H/9341-3
Order Number LM741J, LM741J/883,
LM741CM, LM741CN or LM741EN
See NS Package Number J08A, M08A or N08E

